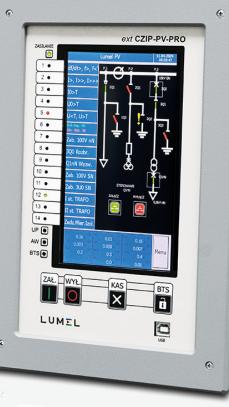
LUMEL



EXTORING OF CONTROL RELAY

CE

RES/PV RELAYS TO MV/LV NETWORKS

- extCZIP®-PV PRO relay is designed for switchgear at the connection points of renewable energy sources, in particular photovoltaic power plants to MV and LV distribution networks, as well as for the micro-installations.
- It performs voltage and current measurements on both the MV and LV sides.
- It enables measurement using low-power measurement transformers (CR/CRR).
- It ensures compatibility with a three-winding transformer, implementing two measurement paths on the LV side.
- It meets all the requirements for power system protection in photovoltaic power plants.
- It includes underimpedance protection against phase-to-phase faults, which enables the short-circuit detection regardless of the short-circuit current values, making the protection reach independent of the fault type.
- CZIP[®]-Set utility software to support all CZIP[®] system devices, including extCZIP[®]-PV PRO.

extCZIP[®]-PV-PRO INTEGRATED PROTECTION AND CONTROL RELAY

The dynamic development of solar power plants, i.e. photovoltaics (PV), requires the use of specialized protection and control relays that ensure protection against various faults. The protection should apply particularly to electrical devices connected to the network and the network itself.

Specific requirements regarding the protection functions were an inspiration to develop the new design of protection relay featured as **extCZIP®-PV PRO**.

The **extCZIP®-PV PRO** relay is intended for switchgear operating at the connection points of photovoltaic plants to the MV or LV distribution networks, as well as for the micro-installations. The device meets all requirements regarding power system protection for PV plants, specified in the Grid Code of the Polish Distribution System Operators (IRiESD) and the PN-EN 50549-1 and PN-EN 50549-2 standards. It includes protections supplied from both MV and LV voltage circuits. To perform the required functions, the new relay is equipped with additional inputs for voltage and current measurement at the LV side.





extCZIP®-PV PRO

It is built on the basis of proven hardware and software solutions known from the **CZIP**[®] system, including the **CZIP[®]-Set** utility software.

It includes the **underimpedance protection**, which is a possible solution to the phase-to-phase short-circuit problems occurring near the PV plants. Underimpedance protection solves the problems related to the fact that the short-circuit

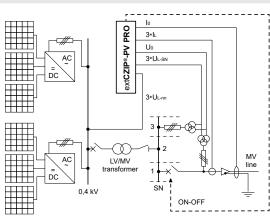
current generated by PV plants is only 10% greater than their rated current.

extCZIP[®]-PV-PRO INTEGRATED PROTECTION AND CONTROL RELAY

CHARACTERISTICS

- programmable logic support (50),
- colour LCD TFT 7" screen, 800x480, with a touch panel,
- bay synoptic diagram presentation with mapping of the switch states,
- switch control from the synoptic screen and using telemechanics (up to 11 switches),
- presentation of the recorded events, measurement values and input or output states,
- 28 or 56 opto-isolated binary inputs,
- 20 or 40 output relays,
- 14 bi-colour programmable LEDs, with on-screen description,
- ON and OFF buttons to control the bay circuit breaker from the device keyboard,
- 512 MB internal memory for recording samples of disturbance recorder, event recorder, energy measurements,
- time synchronization via Ethernet network using SNTP,
- independent communication interfaces: USB, 2 x RS-485, Ethernet 10/100 BASE-TX (optional fibre optic port and CAN-BUS/RS-485),
- communication protocols: DNP 3.0, IEC 60870-5-103 and 104, IEC 61850, Modbus® ASCII / RTU (optional PPM2 protocol on CAN-BUS/RS-485 port),
- 2-bit status monitoring of all switches,
- optional phase current measurement inputs adapted for operation with low-power current transformers based on Rogowski coils.

APPLICATION | RECOMMENDED CONNECTION DIAGRAMS OF A PV PLANT TO THE POWER NETWORK



extCZIP®-PV PRO

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LV/MV transform

0,4 kV

AC

AC

= DC

3*I∟

U٥ 3*UL-SN

3*UL-nr

2

SN

PV plant connection to the MV line with consumers

The PV plant includes the MV/LV transformer and the connection point is upstream in the network.

In the PV plant there is a MV circuit breaker and it is controlled by the extCZIP®-PV PRO.

PV plant connection to the MV network with the customer's line ON-OFF

PRO (1E)

extCZIP

ΜV

line

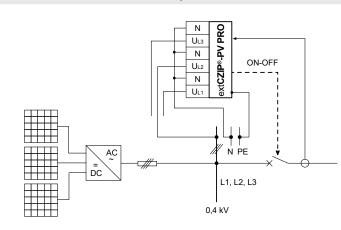
The PV plant includes the MV/LV transformer and it is connected to the MV substation bay (at GPZ or RS) with the customer's line.

If the circuit breaker is located only at the connection point outside the PV plant (e.g. at GPZ substation), then the extCZIP®-PV PRO controls the circuit breaker at LV side.

GP7

extCZIP[®]-PV-PRO INTEGRATED PROTECTION AND CONTROL RELAY

PV plant connection to the LV network (microgeneration)



If a specialized protection relay is used in a micro-installation, then there is no need to install voltage transformers (including the U0 filter) and the 230 V/400 V voltage and phase currents are connected directly from the LV side.

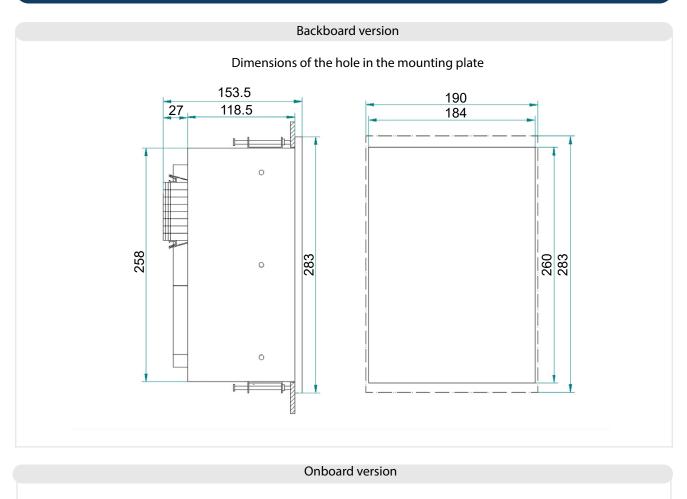
TECHNICAL DATA

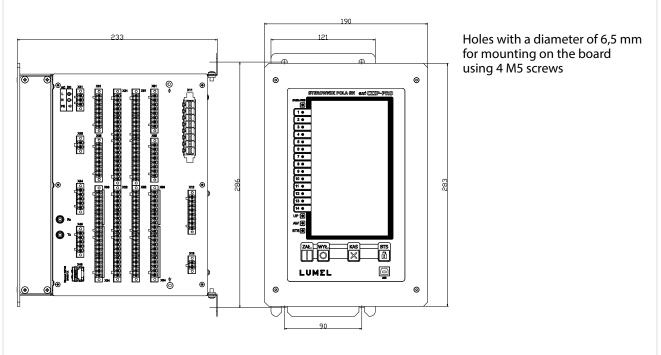
Phase current inputs	V and IVA				
(optionally two sets of inputs - for HV and LV) CURRENT TRANSFORMERS					
Rated current I	5 A or 1 A				
Current range	0200 A				
Maacuramant					
error 0 A > 0,3550 A < 20	00 A < 10% < 1,5% < 10%				
Rated frequency f _n	50 Hz				
Power consumption at $I=I_n$	< 0,5 VA at rated current				
LOW-POWER CURRENT TRANSFORMERS	CR/CRR				
Current range	0.1A150kA				
Measurement Circuit Resistance	50 kΩ				
Phase voltage inputs (MV) two sets of inputs - for compatibility with a three-winding transformer (TWT)					
Rated voltage U _n	100 V				
Voltage range	0130 V				
Measurement error 0130	V < 1,5%				
Rated frequency f _n	50 Hz				
Power consumption at $U=U_n$	< 0,4 VA at rated voltage				
LV phase voltage inputs					
Rated voltage U _n	100 V or 230 V				
Voltage range	0300 V				
Measurement error in the measurement rang	e < 1,5%				
Power consumption at $U=U_n$	< 1,5VA				
Rated frequency f _n	50 Hz				
Continuous voltage withstand	1,4 * U _n				
Zero-sequence voltage inputs					
Rated voltage U_{0n}	100 V				
Voltage range	0130 V				
Measurement error 0130	V < 1,5%				
Rated frequency f _n	50 Hz				
Power consumption at U=U _{on}	< 0,4 VA at rated voltage				

Binary inputs (28 or 56 inputs)						
Input type		opto-isolated				
Rated input voltage	24	4 V DC	220 V DC			
Input voltage range	17	.32 V DC 8	88253 V DC			
Current drain	<	3 mA	< 3 mA			
Output relays (20 d	or 40 outputs)					
Rated voltage		220 V	24 V			
Continuous current o	arrying capacity	1	5 A			
Breaking capacity of	the inductioncirc	uit				
• 220 V DC, L/R = 40 r	ns	0,1 A				
• 220 V AC, cos φ = 0,4		2 A				
Circuit breaker cor	nection circuits	;				
Rated voltage		220 V	24 V			
Continuous current o	arrying capacity	8	3 A			
Breaking capacity of the induction circuit						
• 220 V DC, L/R = 40 ms		1,2 A / 300 cycles				
Duration of the switch-off impulse		min. 0,1 s				
Duration of the switch-on impulse min. 0,1 s						
Power supply						
Power supply						
 nominal auxiliary voltage 	220 V DC 90300 V DC	230 V AC 85265 V AC	24 V DC 1965 V DC			
 auxiliary power consumption 	< 20 W					
Environmental conditions						
 operating temperature 		-10+55°C				
storage temperature		-20+70°C				
• altitude		≤ 2000 m				
 relative humidity 		595%				
Weight		6 kg				
Dimensions		283 x 190 x 153,5 mm backboard version				
		283 x 190 x 233 mm onboard version				
-			d version 50			
Case protection degree		acc. to PN-EN 60529				

extCZIP®-PV-PRO INTEGRATED PROTECTION AND CONTROL RELAY

DIMENSIONS





extCZIP[®]-PV-PRO

INTEGRATED PROTECTION AND CONTROL RELAY

PROTECTION FUNCTIONS AVAILABLE AT extCZIP®-PV PRO

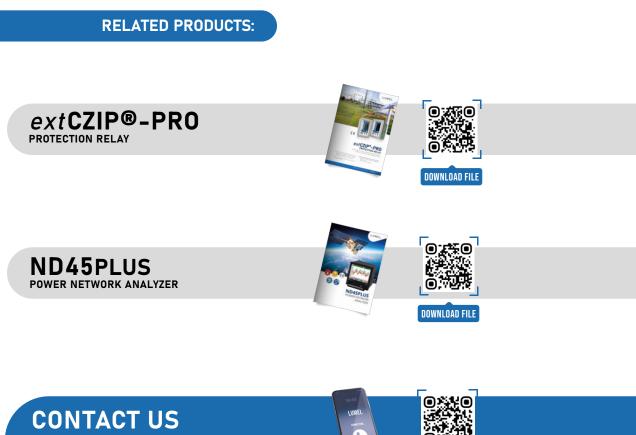
extCZIP®-PV PRO is almost identical to **extCZIP®-PRO (1E)** in terms of protections supplied from **MV circuits**. It is equipped with **overcurrent and underimpedance** protection for phase faults, as well as **voltage**, **frequency and earth-fault** protection. Additionally, the **overvoltage** protection has been introduced, the criterion of which is the average voltage value from the last 10 minutes, in accordance with the standards' requirements. It will operate if the start-up condition is met by one of the three phase-to-phase voltages within the set time.

Undervoltage I stage U 1100 V 0.0560 s Undervoltage I stage U< 1100 V 0.0560 s Overvoltage I stage U> 100130 V 0.0560 s Overvoltage I stage U> 100130 V 0.0560 s Overvoltage for the 10 min. average U10> 110130 V - Negative sequence overvoltage autonomous U0> 2100 V 0.0560 s Underfrequency I stage f< 4550 Hz 0.0110 s Underfrequency I stage f> 5055 Hz 0.0110 s Overfrequency I stage f> 5055 Hz 0.0110 s Overfrequency I stage f> 5055 Hz 0.0110 s Overfrequency I stage f> 5055 Hz 0.0110 s Directional overpower I stage f> 5055 Hz 0.0110 s Directional overpower I stage P3> 109900 W 0.1600 s Directional overpower I stage Q3> 109900 Var 0.1600 s Directional overpower I stage U< 1400 V	Protections supplied from MV voltage circuits			
Undervoltage Istage U<	Criterion	Symbol	Criterion setting range	Time setting range
Overvoltage Istage U> 100130 V 0.0560 s Overvoltage Istage U>> 100130 V 0.05560 s Overvoltage for the 10 min. average U10> 110130 V - Negative sequence overvoltage U0eg> 1100 V 0.05560 s Residual overvoltage autonomous U0 2100 V 0.05560 s Underfrequency Istage f<	Undervoltage I stage	U<	1100 V	0,0560 s
Overvoltage II stageUD>100130 V0.0560 sOvervoltage for the 10 min.averageU10>1.10.01.00560 sNegative sequence overvoltageUneg>1100 V0.0560 sResidual overvoltage autonomousU0>2100 V0.0560 sUnderfrequency I stagef<	Undervoltage II stage	U<<	1100 V	0,0560 s
Overroltage for the 10 min. averageU10>110130 V.Negative sequence overvoltageUneg>1100 V0.0560 sResidual overvoltage autonomousU0>2100 V0.0560 sUnderfrequency I stagef<	Overvoltage I stage	U>	100130 V	0,0560 s
Negative sequence overvoltage Uneg> 1100 V 0.0560 s Residual overvoltage autonomous U0> 2100 V 0.0560 s Residual overvoltage autonomous I0> 2100 V 0.0560 s Underfrequency I stage f<	Overvoltage II stage	U>>	100130 V	0,0560 s
Residual overoltage autonomous UD> 2100 V 0.0560 s Residual overoltage autonomous UD> 2100 V 0.0560 s Underfrequency I stage f<	Overvoltage for the 10 min. average	U10>	110130 V	-
Underfrequency I stagef44550 Hz0.0110 sUnderfrequency I stagef<	Negative sequence overvoltage	Uneg>	1100 V	0,0560 s
Inderfrequency II stage f< 4550 Hz 0.0110 s Overfrequency I stage f> 5055 Hz 0.0110 s Overfrequency I stage f> 5055 Hz 0.0110 s Anti-islanding LoM dfdt< and dfdt> 0.125 Hz/s 0.0110 s Anti-islanding LoM dfdt< and dfdt> 0.1500 V/s 0.0560 s Rated of change of voltage (increase) dU/dt increase 1500 V/s 0.0560 s Directional overpower I stage P3> 109900 W 0.1600 s Directional overpower II stage Q3> 109900 Wa 0.1600 s Directional overpower (reactive power) II stage Q3> 109900 Va 0.1600 s Directional overpower (reactive power) II stage Q3> 109900 Va 0.1600 s Protections supplied from LV voltage circuits (vith or wit/LV tar/streamer) Time setting range Q3> 109900 Va 0.060 s Undervoltage I stage U 1400 V 0.0560 s Q3> 100500 V 0.0560 s Overvoltage I stage U 1600 X 0.0560 s <td>Residual overvoltage autonomous</td> <td>U0></td> <td>2100 V</td> <td>0,0560 s</td>	Residual overvoltage autonomous	U0>	2100 V	0,0560 s
Overfrequency i stage Interfere Output Overfrequency i stage f> S055 Hz 0.0110 s Overfrequency il stage f> S055 Hz 0.0110 s Anti-islanding LoM dfdt< and dfdt> 0.125 Hz/s 0.0110 s Rated of change of voltage (increase) dU/dt increase 1500 V/s 0.0560 s Directional overpower I stage dU/dt decrease 1100 V/s 0.0560 s Directional overpower (reactive power) I stage Q3> 109900 Wa 0,1600 s Directional overpower (reactive power) I stage Q3> 109900 var 0,1600 s Directional overpower (reactive power) I stage Q3> 109900 var 0,1600 s Directional overpower (reactive power) I stage Q3> 109900 var 0,1600 s Directional overpower (reactive power) I stage Q3> 109900 var 0,1600 s Protections supplied from LV voltage circuits (with or wit>	Underfrequency I stage	f<	4550 Hz	0,0110 s
Overfrequency II stage If is an origination of the stage If is a stage Solution of the stage Optimized Overfrequency II stage dfd< and dfdt> $0,125$ Hz/s $0,0110$ s Anti-islanding LoM dfdt< and dfdt> $0,125$ Hz/s $0,0110$ s Rated of change of voltage (increase) dU/dt increase 1500 V/s $0,0560$ s Directional overpower I stage P3> 109900 W $0,1600$ s Directional overpower I stage Q3> 109900 Wa $0,1600$ s Directional overpower (reactive power) I stage Q3> 109900 Var $0,1600$ s Directional overpower (reactive power) I stage Q3> 109900 Var $0,1600$ s Directional overpower (reactive power) I stage Q3> 109900 Var $0,1600$ s Directional overpower (reactive power) I stage Q3> 109900 Var $0,1600$ s Directional overpower (reactive power) I stage Q3> 109900 Var $0,060$ s Undervoltage I stage U 1	Underfrequency II stage	f<<	4550 Hz	0,0110 s
Anti-islanding LoM dfdt< and dfdt> 0,125 Hz/s 0,0110 s Anti-islanding LoM dfdt< and dfdt> 0,125 Hz/s 0,0110 s Rated of change of voltage (increase) dU/dt increase 1100 V/s 0,0560 s Bated of change of voltage (decrease) dU/dt decrease 1100 V/s 0,0560 s Directional overpower I stage P3> 109900 W 0,1600 s Directional overpower (reactive power) I stage Q3> 109900 var 0,1600 s Directional overpower (reactive power) I stage Q3> 109900 var 0,1600 s Directional overpower (reactive power) I stage Q3> 109900 var 0,1600 s Protections supplied from LV voltage circuits (with or WL/LV transformer) Time setting range U1400 V 0,0560 s Undervoltage I stage U 1400 V 0,0560 s 0 Overvoltage I stage U 1400 V 0,0560 s Overvoltage I stage U 1.00500 V 0,0560 s Overvoltage I stage f<	Overfrequency I stage	f>	5055 Hz	0,0110 s
Rated of change of voltage (increase) dU/dt increase 1500 V/s 0.0560 s Rated of change of voltage (decrease) dU/dt decrease 1100 V/s 0.0560 s Directional overpower I stage P3> 109900 W 0.1600 s Directional overpower II stage Q3> 109900 Var 0.1600 s Directional overpower (reactive power) I stage Q3> 109900 Var 0.1600 s Directional overpower (reactive power) II stage Q3> 109900 Var 0.1600 s Directional overpower (reactive power) II stage Q3> 109900 Var 0.1600 s Directional overpower (reactive power) II stage Q3> 109900 var 0.1600 s Directional overpower (reactive power) II stage Q3> 109900 var 0.1600 s Undervoltage I stage U 1400 V 0.0560 s 0.0560 s Undervoltage II stage U 1400 V 0.0560 s 0.0560 s Overvoltage II stage U10> 100500 V 0.0560 s 0.0560 s Overvoltage II stage III stage III stage <	Overfrequency II stage	f>>	5055 Hz	0,0110 s
Rated of voltage (decrease) dU/dt decrease 1100 V/s 0,0560 s Directional overpower I stage P3> 109900 W 0,1600 s Directional overpower II stage P3> 109900 W 0,1600 s Directional overpower (reactive power) I stage Q3> 109900 Var 0,1600 s Directional overpower (reactive power) II stage Q3> 109900 var 0,1600 s Directional overpower (reactive power) II stage Q3> 109900 var 0,1600 s Directional overpower (reactive power) II stage Q3> 109900 var 0,1600 s Directional overpower (reactive power) II stage Q3> 109900 var 0,1600 s Directional overpower (reactive power) II stage Q3> 109900 var 0,1600 s Protections supplied from LV voltage circuits (with or with-with the MV/LV trasformer) 0,0560 s 0,0560 s Undervoltage II stage U 1400 V 0,0560 s 0,0560 s Overvoltage II stage U 100500 V 0,0560 s 0,0560 s Overvoltage II stage f<	Anti-islanding LoM	dfdt< and dfdt>	0,125 Hz/s	0,0110 s
Directional overpower I stageP3>109900 W0,1600 sDirectional overpower II stageP3>>109900 Wa0,1600 sDirectional overpower (reactive power) I stageQ3>109900 var0,1600 sDirectional overpower (reactive power) II stageQ3>>109900 var0,1600 sProtections supplied from LV voltage circuits (with or without the MVLV transformer)Time setting rangeCriterionSymbolCriterion setting rangeTime setting rangeUndervoltage I stageU<	Rated of change of voltage (increase)	dU/dt increase	1500 V/s	0,0560 s
Directional overpower II stage P3>> 109900 W 0,1600 s Directional overpower (reactive power) I stage Q3> 109900 var 0,1600 s Directional overpower (reactive power) II stage Q3> 109900 var 0,1600 s Protections supplied from LV voltage circuits (with or wit-bet the MV/LV transformer) 0,1600 s 0,1600 s Protections supplied from LV voltage circuits (with or wit-bet the MV/LV transformer) Time setting range Time setting range Undervoltage I stage U 1400 V 0,0560 s Overvoltage I stage U 1400 V 0,0560 s Overvoltage I stage U 1400 V 0,0560 s Overvoltage I stage U 1.00500 V 0,0560 s Overvoltage I stage U 100500 V 0,0560 s Overvoltage I stage U 100500 V 0,0560 s Overvoltage I stage U 100500 V 0,0110 s Overvoltage I stage F 4750 Hz 0,0110 s Overfrequency I stage f 5052 Hz 0,0110 s	Rated of change of voltage (decrease)	dU/dt decrease	1100 V/s	0,05…60 s
Directional overpower (reactive power) I stageQ3>109900 var0,1600 sDirectional overpower (reactive power) II stageQ3>>109900 var0,1600 sProtections supplied from LV voltage circuits (with or wit>+++ MV/LV transformer)Trime setting rangeCriterionSymbolCriterion setting rangeTime setting rangeUndervoltage I stageU<	Directional overpower I stage	P3>	109900 W	0,1600 s
Directional overpower (reactive power) II stage Q3>> 109900 var 0,1600 s Protections supplied from LV voltage circuits (with or wit>ut the MV/LV transformer) Time setting range Time setting range Criterion Symbol Criterion setting range Time setting range Undervoltage I stage U<	Directional overpower II stage	P3>>	109900 W	0,1600 s
Protections supplied from LV voltage circuits (with or with-ut the MV/LV transformer)CriterionSymbolCriterion setting rangeTime setting rangeUndervoltage I stageU1400 V0.0560 sUndervoltage II stageU<	Directional overpower (reactive power) I stage	Q3>	109900 var	0,1600 s
Criterion Symbol Criterion setting range Time setting range Undervoltage I stage U 1400 V 0,0560 s Undervoltage II stage U<	Directional overpower (reactive power) II stage	Q3>>	109900 var	0,1600 s
Undervoltage I stage U< 1400 V 0,0560 s Undervoltage II stage U<	Protections supplied from LV voltage circuits (with or	without the MV/LV trar	nsformer)	
Undervoltage II stage U< 1400 V 0,0560 s Overvoltage I stage U> 100500 V 0,0560 s Overvoltage II stage U> 100500 V 0,0560 s Overvoltage II stage U> 100500 V 0,0560 s Overvoltage II stage U> 100500 V 0,0560 s Overvoltage for the 10 min. average U10> 100470 V - Underfrequency I stage f<	Criterion	Symbol	Criterion setting range	Time setting range
Overvoltage I stage U> 100500 V 0,0560 s Overvoltage II stage U>> 100500 V 0,0560 s Overvoltage II stage U>> 100500 V 0,0560 s Overvoltage I stage U1>> 100500 V 0,0560 s Overvoltage I stage U10> 100470 V - Underfrequency I stage f 4750 Hz 0,0110 s Overfrequency I stage f<	Undervoltage I stage	U<	1400 V	0,0560 s
Overvoltage II stage U>> 100500 V 0,0560 s Overvoltage for the 10 min. average U10> 100470 V - Underfrequency I stage f 4750 Hz 0,0110 s Underfrequency II stage f<	Undervoltage II stage	U<<	1400 V	0,0560 s
Overvoltage for the 10 min. average U10> 100470 V - Underfrequency I stage f<	Overvoltage I stage	U>	100500 V	0,0560 s
Underfrequency I stage f 4750 Hz 0,0110 s Underfrequency I stage f<	Overvoltage II stage	U>>	100500 V	0,0560 s
Underfrequency II stage f< 4750 Hz 0,0110 s Overfrequency I stage f> 5052 Hz 0,0110 s Overfrequency II stage f>> 5052 Hz 0,0110 s Overfrequency II stage f>> 5052 Hz 0,0110 s Overfrequency II stage f>> 0,125 Hz/s 0,0110 s Directional overpower I stage P3> 0,110 kW 0,1600 s Directional overpower (reactive power) I stage Q3> 0,110 kvar 0,1600 s	Overvoltage for the 10 min. average	U10>	100470 V	-
Overfrequency I stage f> 5052 Hz 0,0110 s Overfrequency I stage f>> 5052 Hz 0,0110 s Overfrequency II stage f>> 5052 Hz 0,0110 s Anti-islanding LoM dfdt< and dfdt> 0,125 Hz/s 0,0110 s Directional overpower I stage P3> 0,110 kW 0,1600 s Directional overpower (reactive power) I stage Q3> 0,110 kvar 0,1600 s	Underfrequency I stage	f<	4750 Hz	0,0110 s
Overfrequency II stage f>> 5052 Hz 0,0110 s Anti-islanding LoM dfdt< and dfdt> 0,125 Hz/s 0,0110 s Directional overpower I stage P3> 0,110 kW 0,1600 s Directional overpower II stage P3> 0,110 kW 0,1600 s Directional overpower (reactive power) I stage Q3> 0,110 kvar 0,1600 s	Underfrequency II stage	f<<	4750 Hz	0,0110 s
Anti-islanding LoM dfdt< and dfdt> 0,125 Hz/s 0,0110 s Directional overpower I stage P3> 0,110 kW 0,1600 s Directional overpower (reactive power) I stage Q3> 0,110 kwar 0,1600 s	Overfrequency I stage	f>	5052 Hz	0,0110 s
Directional overpower I stageP3>0,110 kW0,1600 sDirectional overpower II stageP3>>0,110 kW0,1600 sDirectional overpower (reactive power) I stageQ3>0,110 kvar0,1600 s	Overfrequency II stage	f>>	5052 Hz	0,0110 s
Directional overpower II stageP3>>0,110 kW0,1600 sDirectional overpower (reactive power) I stageQ3>0,110 kvar0,1600 s	Anti-islanding LoM	dfdt< and dfdt>	0,125 Hz/s	0,0110 s
Directional overpower (reactive power) I stage Q3> 0,110 kvar 0,1600 s	Directional overpower I stage	P3>	0,110 kW	0,1600 s
	Directional overpower II stage	P3>>	0,110 kW	0,1600 s
Directional overpower (reactive power) II stage Q3>> 0,110 kvar 0,1600 s	Directional overpower (reactive power) I stage	Q3>	0,110 kvar	0,1600 s
	Directional overpower (reactive power) Il stage	Q3>>	0,110 kvar	0,1600 s

The CZIP*-PV PRO is also equipped with all the protection functions supplied from the current circuits, similarly to the extCZIP-PRO (1E) application for a MV line with local generation.

extCZIP®-PV-PRO

INTEGRATED PROTECTION AND CONTROL RELAY



⊠ czip@lumel.com.pl ⊠ export@lumel.com.pl



LUMEL

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